

**MICROCHIP****TC4426AM/TC4427AM/TC4428AM**

1.5A Dual High-Speed Power MOSFET Drivers

Features

- High Peak Output Current: 1.5A
- Wide Input Supply Voltage Operating Range:
 - 4.5V to 18V
- High Capacitive Load Drive Capability:
 - 1000 pF in 25 ns (typ.)
- Short Delay Times: 30 ns (typ.)
- Matched Rise, Fall and Delay Times
- Low Supply Current:
 - With Logic '1' Input – 1 mA (typ.)
 - With Logic '0' Input – 100 μ A (typ.)
- Low Output Impedance: 7 Ω (typ.)
- Latch-Up Protected: Will Withstand 0.5A Reverse Current
- Input: Will Withstand Negative Inputs Up to 5V
- ESD Protected: 4 kV
- Pin-compatible with the TC426M/TC427M/TC428M and TC4426M/TC4427M/TC4428M
- Wide Operating Temperature Range:
 - -55°C to +125°C
- See TC4426A/TC4427A/TC4428A Data Sheet (DS21423) for additional temperature range and packaging offerings

Applications

- Switch-mode Power Supplies
- Line Drivers
- Pulse Transformer Drive

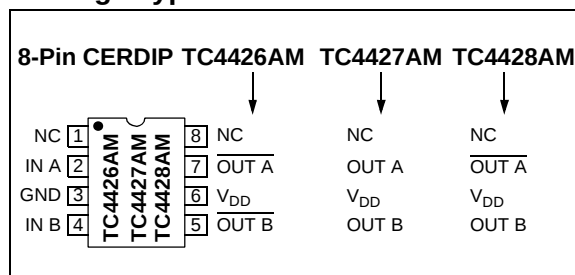
General Description

The TC4426AM/TC4427AM/TC4428AM are improved versions of the earlier TC4426M/TC4427M/TC4428M family of MOSFET drivers. In addition to matched rise and fall times, the TC4426AM/TC4427AM/TC4428AM devices have matched leading and falling edge propagation delay times.

These devices are highly latch-up resistant under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking (of either polarity) occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of reverse current (of either polarity) being forced back into their outputs. All terminals are fully protected against Electrostatic Discharge (ESD) up to 4 kV.

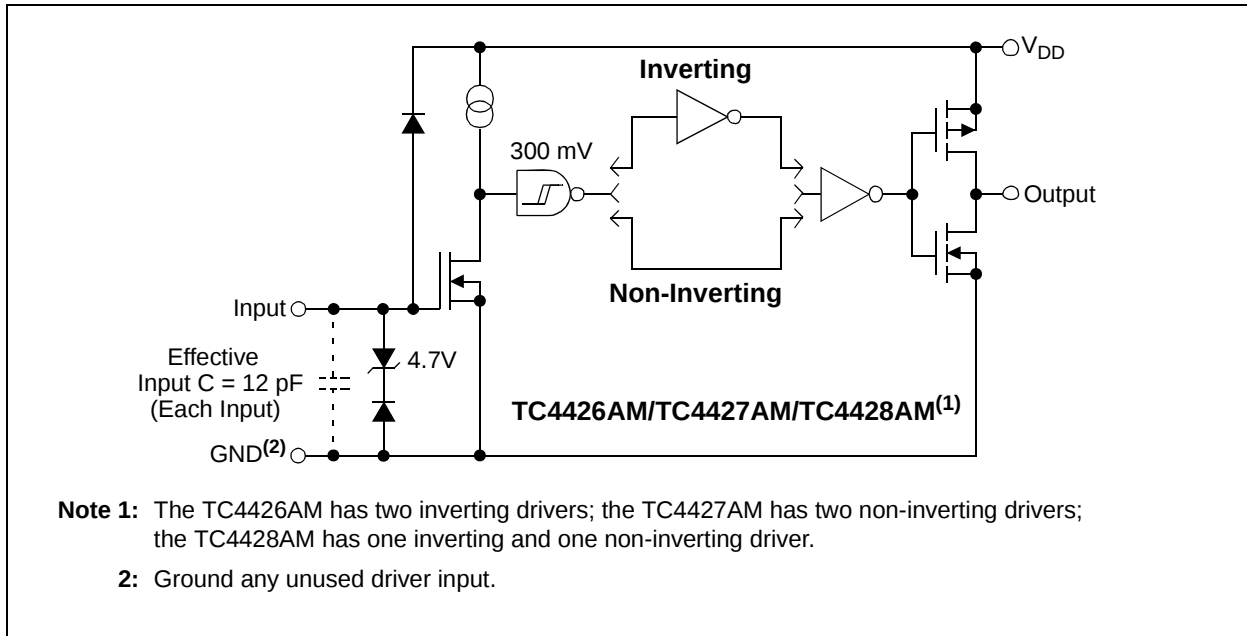
The TC4426AM/TC4427AM/TC4428AM MOSFET drivers can easily charge/discharge 1000 pF gate capacitances in under 30 ns, while providing low enough impedances in both the on and off states to ensure the MOSFET's intended state will not be affected, even by large transients.

Package Types



TC4426AM/TC4427AM/TC4428AM

Functional Block Diagram



TC4426AM/TC4427AM/TC4428AM

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Supply Voltage+22V
Input Voltage, IN A or IN B ($V_{DD} + 0.3V$) to (GND – 5V)

† **Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, over operating temperature range with $4.5V \leq V_{DD} \leq 18V$.						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Input						
Logic '1', High Input Voltage	V_{IH}	2.4	—	—	V	
Logic '0', Low Input Voltage	V_{IL}	—	—	0.8	V	
Input Current	I_{IN}	-1.0 -10	— —	+1.0 +10	μA	$0V \leq V_{IN} \leq V_{DD}$
Output						
High Output Voltage	V_{OH}	$V_{DD} - 0.025$	—	—	V	DC TEST
Low Output Voltage	V_{OL}	—	—	0.025	V	DC TEST
Output Resistance	R_O	—	7	9	Ω	$I_{OUT} = 10\text{ mA}$, $V_{DD} = 18V$, $T_A = +25^\circ C$
		—	8	12		$-55^\circ C \leq T_A \leq +125^\circ C$
Peak Output Current	I_{PK}	—	1.5	—	A	$V_{DD} = 18V$
Latch-Up Protection Withstand Reverse Current	I_{REV}	—	>0.5	—	A	Duty cycle $\leq 2\%$, $t \leq 300\text{ }\mu s$ $V_{DD} = 18V$
Switching Time (Note 1)						
Rise Time	t_R	—	25	35	ns	$T_A = +25^\circ C$
		—	30	40		$-55^\circ C \leq T_A \leq +125^\circ C$, Figure 4-1
Fall Time	t_F	—	25	35	ns	$T_A = +25^\circ C$
		—	30	40		$-55^\circ C \leq T_A \leq +125^\circ C$, Figure 4-1
Delay Time	t_{D1}	—	30	35	ns	$T_A = +25^\circ C$
		—	38	50		$-55^\circ C \leq T_A \leq +125^\circ C$, Figure 4-1
Delay Time	t_{D2}	—	30	35	ns	$T_A = +25^\circ C$
		—	38	50		$-55^\circ C \leq T_A \leq +125^\circ C$, Figure 4-1
Power Supply						
Power Supply Current	I_S	— —	1.0 0.1	2.0 0.2	mA	$V_{IN} = 3V$ (Both inputs)
						$V_{IN} = 0V$ (Both inputs), $V_{DD} = 18V$

Note 1: Switching times ensured by design.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all parameters apply with $4.5V \leq V_{DD} \leq 18V$.						
Parameters	Sym	Min	Typ	Max	Units	Conditions
Temperature Ranges						
Specified Temperature Range (M)	T_A	-55	—	+125	$^\circ C$	
Maximum Junction Temperature	T_J	—	—	+150	$^\circ C$	
Storage Temperature Range	T_A	-65	—	+150	$^\circ C$	
Package Thermal Resistances						
Thermal Resistance, 8L-CERDIP	θ_{JA}	—	150	—	$^\circ C/W$	

TC4426AM/TC4427AM/TC4428AM

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, over operating temperature range with $4.5V \leq V_{DD} \leq 18V$.

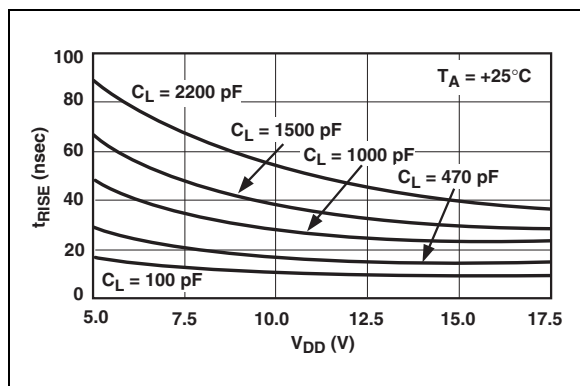


FIGURE 2-1: Rise Time vs. Supply Voltage.

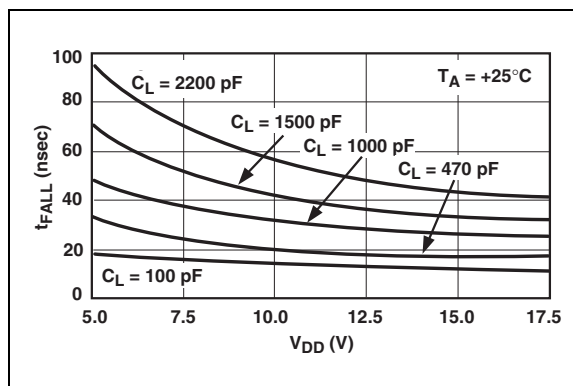


FIGURE 2-4: Fall Time vs. Supply Voltage.

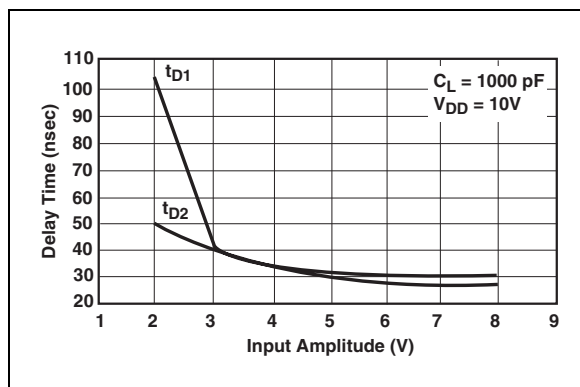


FIGURE 2-2: Delay Time vs. Input Amplitude.

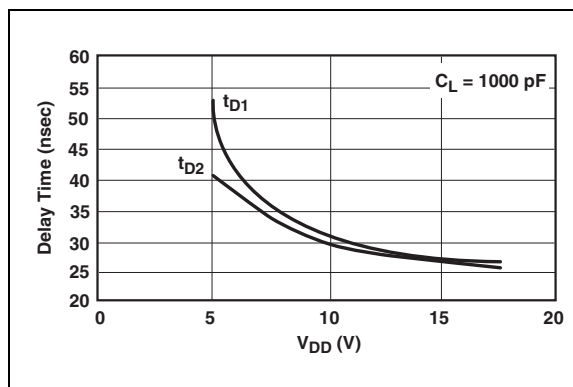


FIGURE 2-5: Propagation Delay Time vs. Supply Voltage.

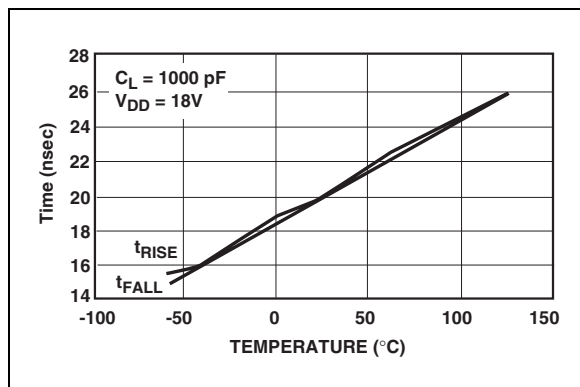


FIGURE 2-3: Rise and Fall Times vs. Temperature.

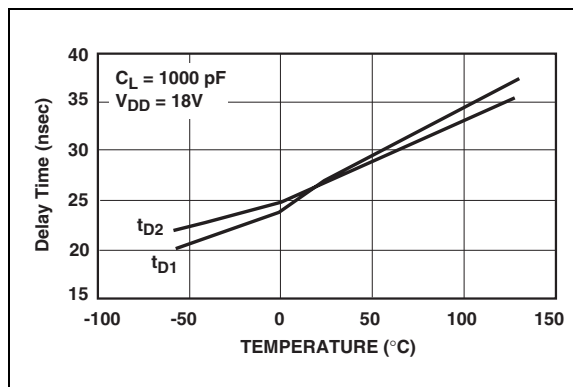


FIGURE 2-6: Propagation Delay Time vs. Temperature.

TC4426AM/TC4427AM/TC4428AM

Note: Unless otherwise indicated, over operating temperature range with $4.5\text{V} \leq V_{DD} \leq 18\text{V}$.

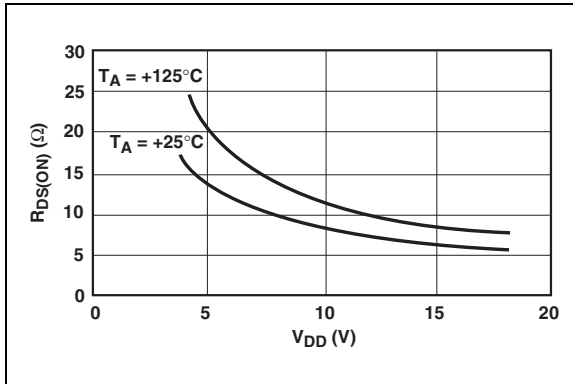


FIGURE 2-7: High-State Output Resistance.

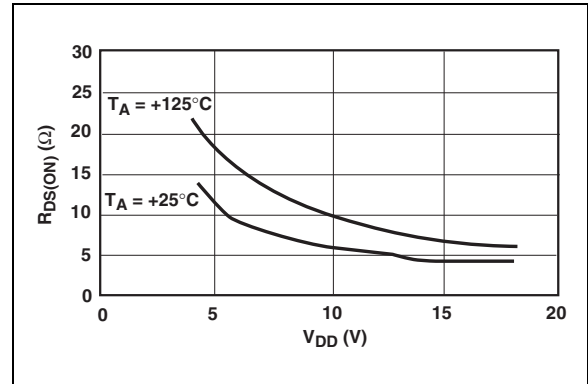


FIGURE 2-10: Low-State Output Resistance.

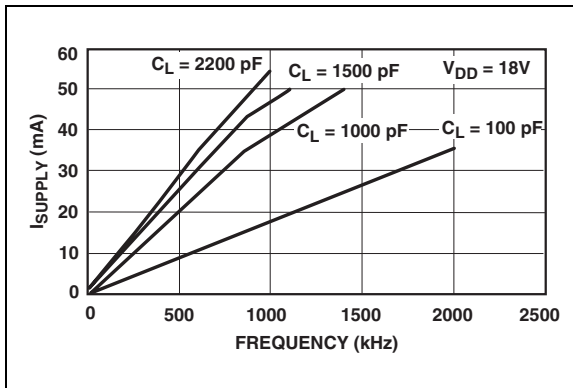


FIGURE 2-8: Supply Current vs. Frequency.

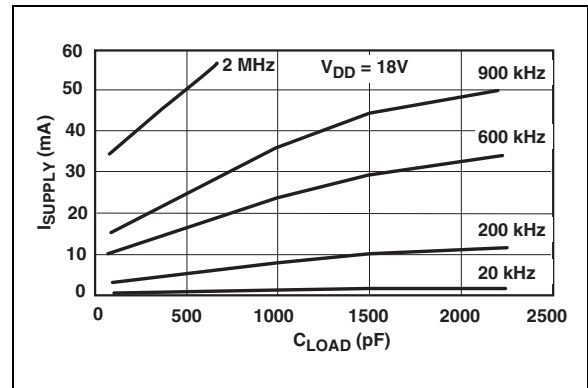


FIGURE 2-11: Supply Current vs. Capacitive Load.

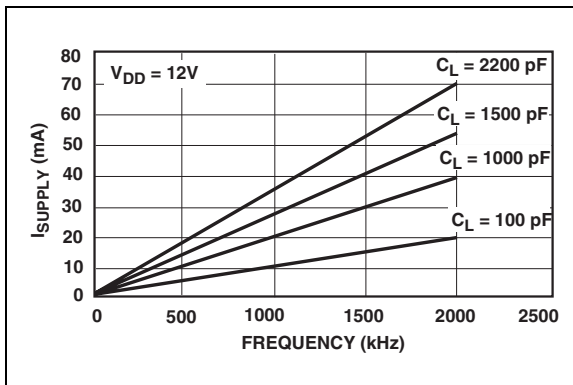


FIGURE 2-9: Supply Current vs. Frequency.

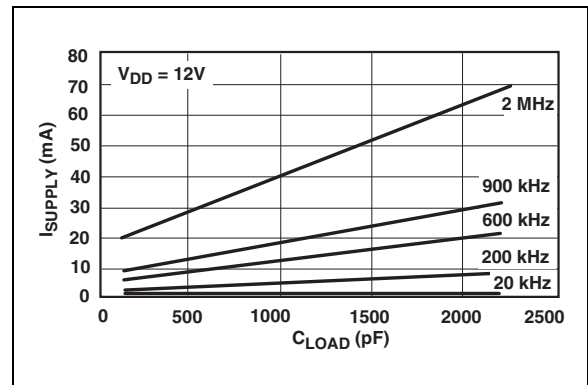


FIGURE 2-12: Supply Current vs. Capacitive Load.

TC4426AM/TC4427AM/TC4428AM

Note: Unless otherwise indicated, over operating temperature range with $4.5V \leq V_{DD} \leq 18V$.

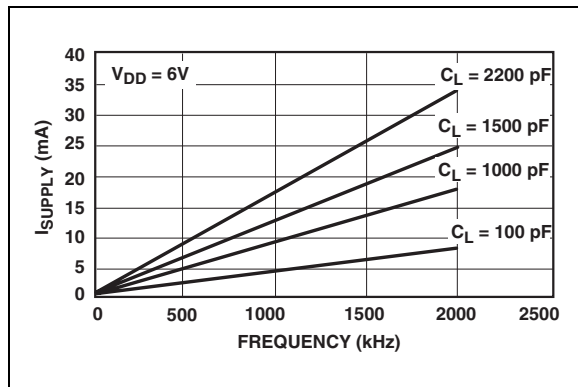


FIGURE 2-13: Supply Current vs. Frequency.

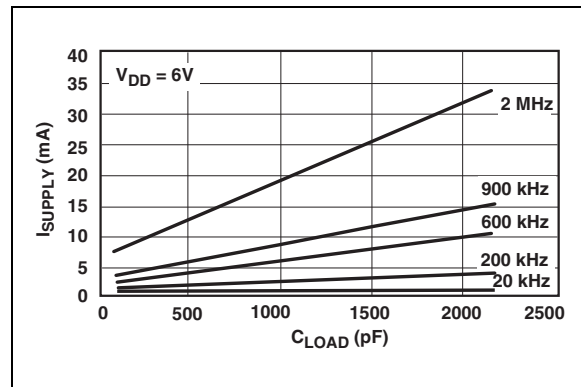


FIGURE 2-15: Supply Current vs. Capacitive Load.

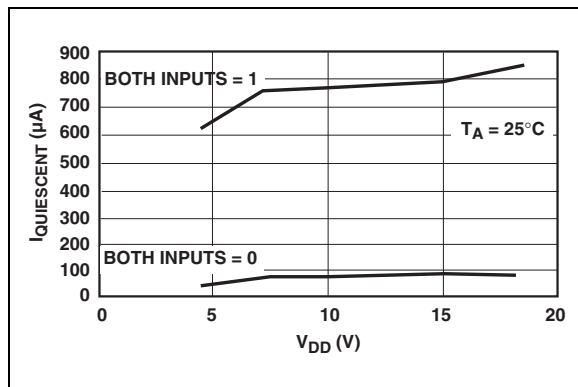


FIGURE 2-14: Quiescent Supply Current vs. Voltage.

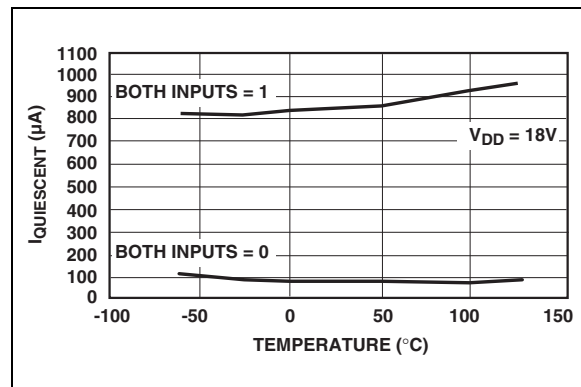


FIGURE 2-16: Quiescent Supply Current vs. Temperature.

TC4426AM/TC4427AM/TC4428AM

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

8-Pin Cerdip	Symbol	Description
1	NC	No connection
2	IN A	Input A
3	GND	Ground
4	IN B	Input B
5	OUT B	Output B
6	V _{DD}	Supply input
7	OUT A	Output A
8	NC	No connection

3.1 Inputs A & B (IN A and IN B)

MOSFET driver IN A & B are high-impedance, TTL/CMOS-compatible inputs. These inputs also have 300 mV of hysteresis between the high and low thresholds, which prevents output glitching even when the rise and fall time of the input signal is very slow.

3.2 Ground (GND)

The GND pin is the return path for both the bias current and the high peak current that discharges the external load capacitance. The ground pin should be tied into a ground plane or have a very short trace to the bias supply source return.

3.3 Outputs A & B (OUT A and OUT B)

MOSFET driver OUT A & B are low-impedance, CMOS, push-pull style outputs. The pull-down and pull-up devices are of equal strength, making the rise and fall times equivalent.

3.4 Supply Input (V_{DD})

The V_{DD} input is the bias supply for the MOSFET driver and is rated for 4.5V to 18V, with respect to the ground pin. The V_{DD} input should be bypassed with local ceramic capacitors. The value of these capacitors should be chosen based on the capacitive load that is being driven.

TC4426AM/TC4427AM/TC4428AM

4.0 APPLICATIONS INFORMATION

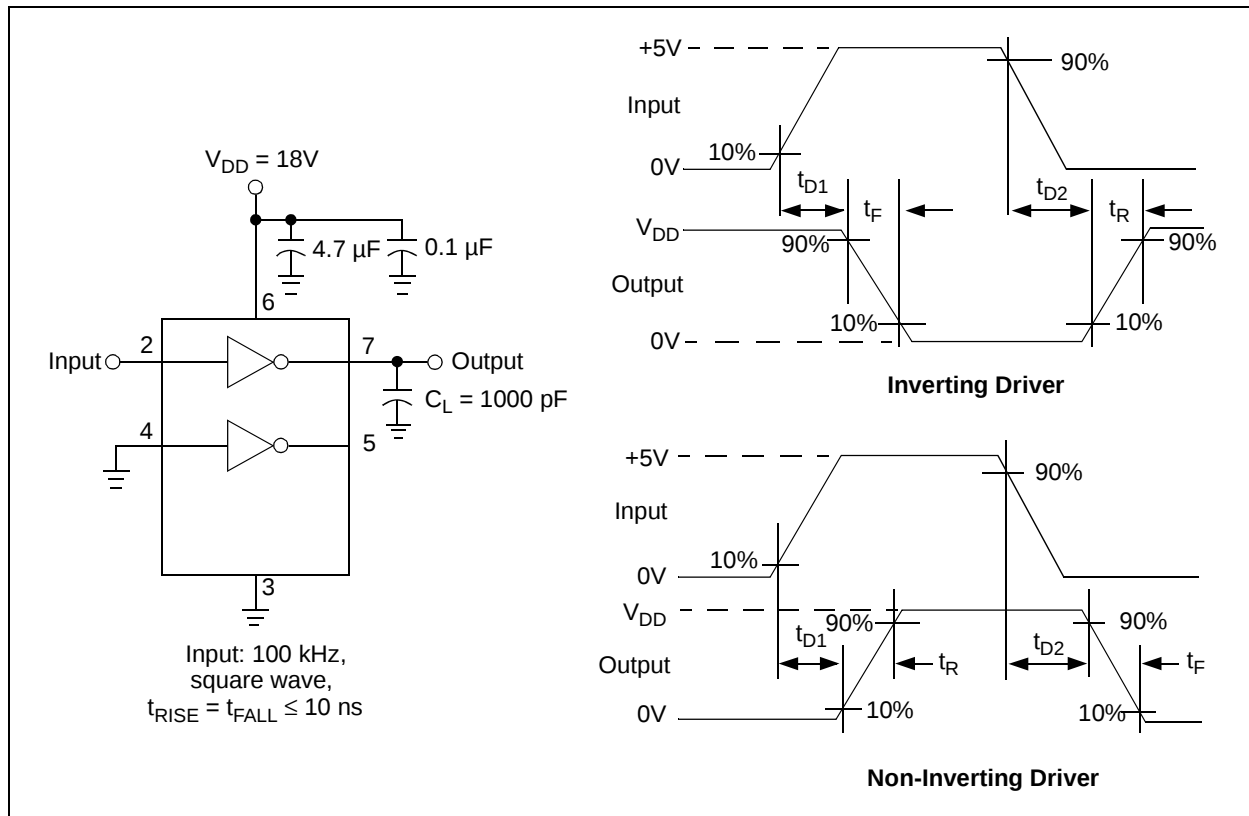


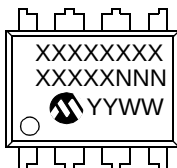
FIGURE 4-1: Switching Time Test Circuit.

TC4426AM/TC4427AM/TC4428AM

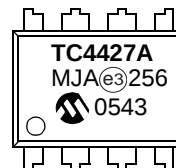
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

8-Lead CERDIP (300 mil)



Example:

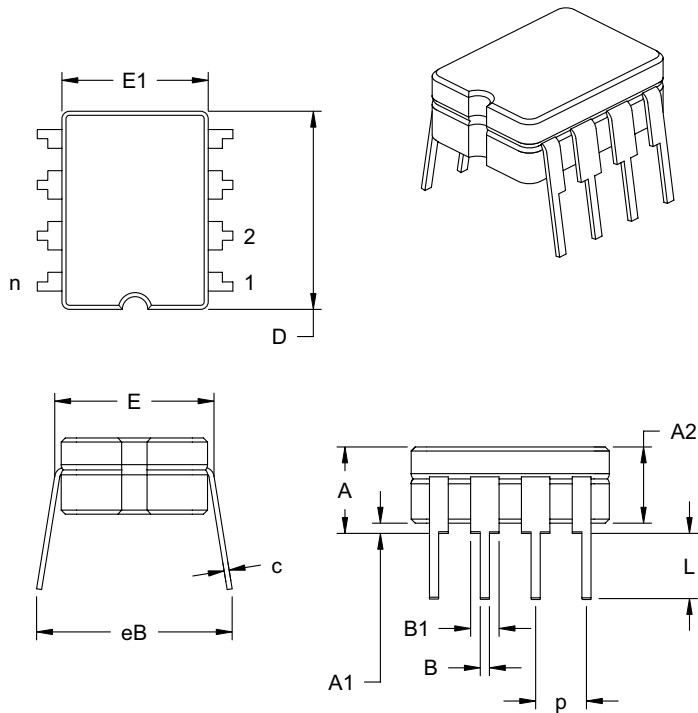


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

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8-Lead Ceramic Dual In-line – 300 mil (CERDIP)



Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	p		.100			2.54	
Top to Seating Plane	A	.160	.180	.200	4.06	4.57	5.08
Standoff §	A1	.020	.030	.040	0.51	0.77	1.02
Shoulder to Shoulder Width	E	.290	.305	.320	7.37	7.75	8.13
Ceramic Pkg. Width	E1	.230	.265	.300	5.84	6.73	7.62
Overall Length	D	.370	.385	.400	9.40	9.78	10.16
Tip to Seating Plane	L	.125	.163	.200	3.18	4.13	5.08
Lead Thickness	c	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.055	.065	1.14	1.40	1.65
Lower Lead Width	B	.016	.018	.020	0.41	0.46	0.51
Overall Row Spacing	eB	.320	.360	.400	8.13	9.15	10.16

*Controlling Parameter

JEDEC Equivalent: MS-030

Drawing No. C04-010

APPENDIX A: REVISION HISTORY

Revision A (February 2005)

- Original Release of this Document.

TC4426AM/TC4427AM/TC4428AM

NOTES:

TC4426AM/TC4427AM/TC4428AM

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.		XX	Examples:	
Device and Temperature Range		Package	a)	TC4426AMJA: 1.5A Dual MOSFET driver, Inverting, -55°C to +125°C 8LD Cerdip package.
Device and Temperature Range:	TC4426AM:	1.5A Dual MOSFET Driver, Inverting, -55°C to +125°C	a)	TC4427AMJA: 1.5A Dual MOSFET driver, Non-Inverting -55°C to +125°C 8LD Cerdip package.
	TC4427AM:	1.5A Dual MOSFET Driver, Non-Inverting, -55°C to +125°C		
	TC4428AM:	1.5A Dual MOSFET Driver, Complementary, -55°C to +125°C	a)	TC4428AMJA: 1.5A Dual MOSFET driver, Complementary, -55°C to +125°C 8LD Cerdip package.
Package:	JA = Ceramic Dual In-line (300 mil Body), 8-lead			

TC4426AM/TC4427AM/TC4428AM

NOTES:

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